Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

Between 0.745 inches and 0.785 inches

Terminal Length:

Between 0.145 inches and 0.200 inches

Overall Height:

Between 0.280 inches and 0.350 inches

Overall Width:

0.300 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Mo-001-ac

Component Name And Quantity:

5 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-40.0 breakdown voltage, collector-to-base, emitter open all transistor and -40.0 breakdown voltage, collector-to-emitter, base open all transistor and -40.0 breakdown voltage, emitter-to-base, collector open all transistor

Current Rating Per Characteristic:

-40.00 nanoamperes zero-gate-voltage source current preset all transistor and -100.00 nanoamperes zero-gate-voltage source current absolute all transistor

Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter all transistor and 200.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

14 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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